## NSN 5961-01-183-6501



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-183-6501 **Inclosure Material:** Metal **Overall Length:** 1.245 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 170.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 110.0 breakdown voltage, collector-to-emitter, base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Lead surfaces gold **Precious Material:** Gold **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

## **NSN 5961-01-183-6501** Transistor - Page 2 of 2



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